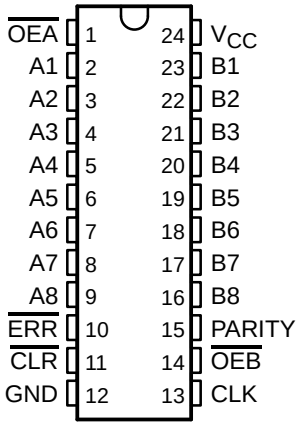
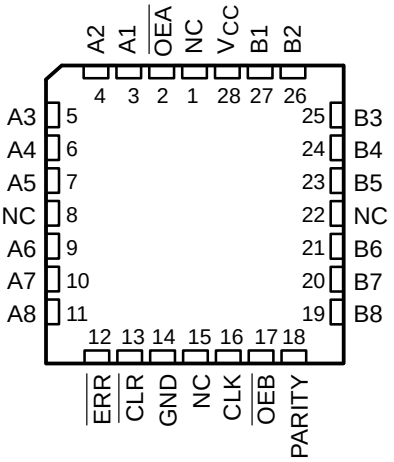
- **State-of-the-Art *EPIC*-ΠB™ BiCMOS Design Significantly Reduces Power Dissipation**
- **ESD Protection Exceeds 2000 V Per MIL-STD-883C, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)**
- **Latch-Up Performance Exceeds 500 mA Per JEDEC Standard JESD-17**
- **Typical V_{OLP} (Output Ground Bounce) < 1 V at V_{CC} = 5 V, T_A = 25°C**
- **High-Drive Outputs (–32-mA I_{OH}, 64-mA I_{OL})**
- **Parity Error Flag With Parity Generator/Checker**
- **Register for Storage of the Parity Error Flag**
- **Package Options Include Plastic Small-Outline (DW) Package, Ceramic Chip Carriers (FK), and Plastic (NT) and Ceramic (JT) DIPs**

SN54ABT833 . . . JT PACKAGE
SN74ABT833 . . . DW OR NT PACKAGE
(TOP VIEW)



SN54ABT833 . . . FK PACKAGE
(TOP VIEW)



NC – No internal connection

description

These ’ABT833 8-bit to 9-bit parity transceivers are designed for communication between data buses. When data is transmitted from the A bus to the B bus, a parity bit is generated. When data is transmitted from the B bus to the A bus with its corresponding parity bit, the open-collector parity-error ($\overline{ERR}$) output indicates whether or not an error in the B data has occurred. The output-enable ($\overline{OEA}$ and $\overline{OEB}$) inputs can be used to disable the device so that the buses are effectively isolated. The ′ABT833 provide true data at their outputs.

A 9-bit parity generator/checker generates a parity-odd (PARITY) output and monitors the parity of the I/O ports with the $\overline{ERR}$ flag. The $\overline{ERR}$ output is clocked into the register on the rising edge of the clock (CLK) input. The error flag register is cleared with a low pulse on the clear ($\overline{CLR}$) input. When both $\overline{OEA}$ and $\overline{OEB}$ are low, data is transferred from the A bus to the B bus and inverted parity is generated. Inverted parity is a forced error condition that gives the designer more system diagnostic capability.

To ensure the high-impedance state during power up or power down, $\overline{OE}$ should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The SN54ABT833 is characterized for operation over the full military temperature range of –55°C to 125°C. The SN74ABT833 is characterized for operation from –40°C to 85°C.

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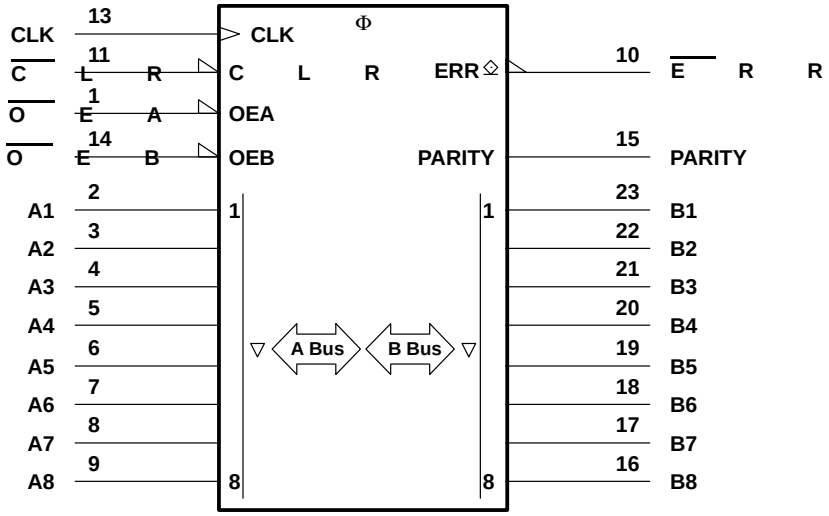
FUNCTION TABLE

INPUTS						OUTPUT AND I/O				FUNCTION
$\overline{OEB}$	$\overline{OEA}$	$\overline{CLR}$	CLK	Ai Σ OF H's	Bi† Σ OF H's	A	B	PARITY	$\overline{ERR}$‡	
L	H	X	X	Odd Even	NA	NA	A	L H	NA	A data to B bus and generate parity
H	L	H	↑	NA	Odd Even	B	NA	NA	H L	B data to A bus and check parity
X	X	L	X	X	X	X	NA	NA	H	Check error-flag register
H	H	H L H H	No↑ No↑ ↑ ↑	X X Odd Even	X	Z	Z	Z	NC H H L	Isolation§
L	L	X	X	Odd Even	Odd Even	NA	NA	H L	NA	Data generate

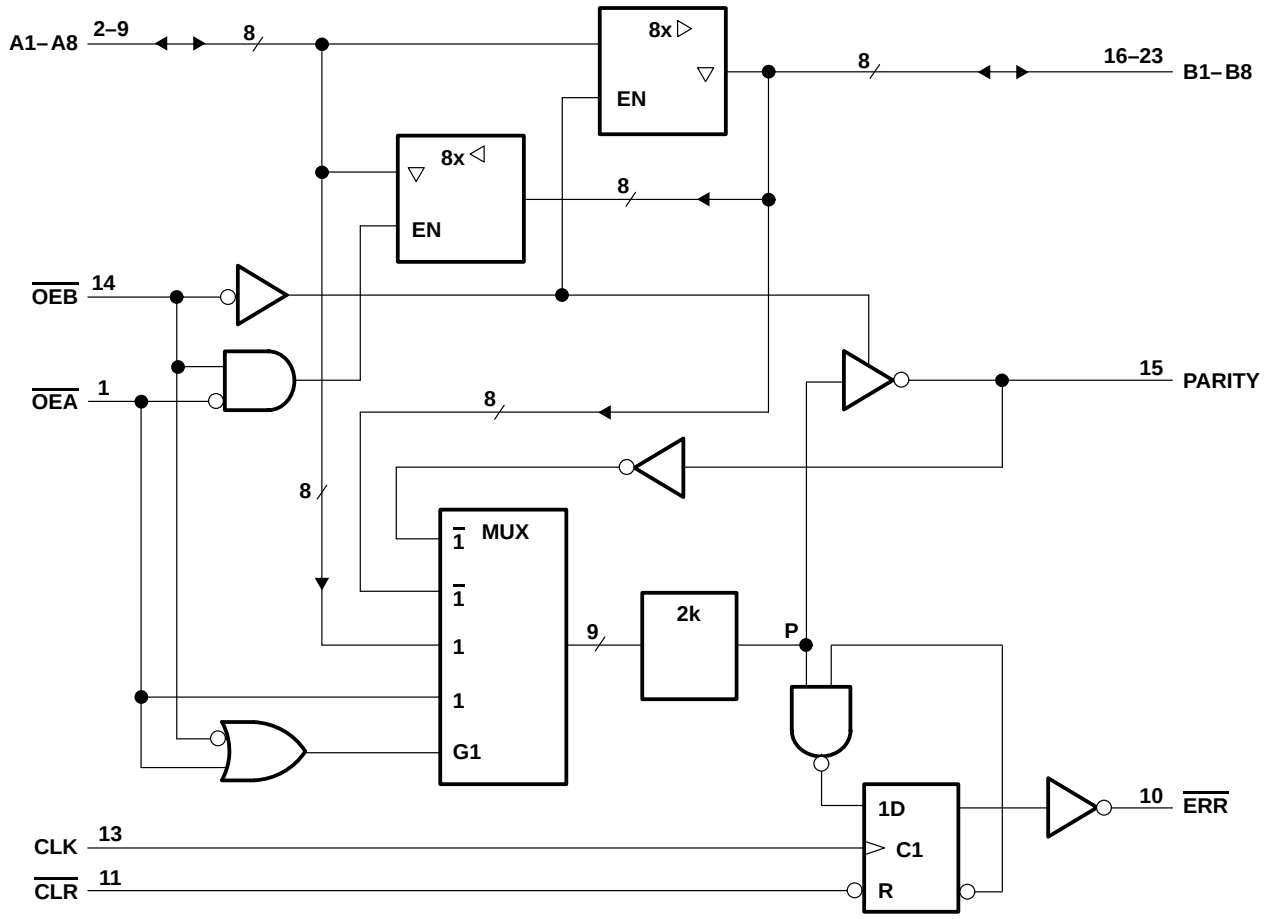
NA = not applicable, NC
†Summation of high-level
‡Output
§In

logic symbol¶



¶ This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.
Pin numbers shown are for the DW, JT, and NT packages.

logic diagram (positive logic)



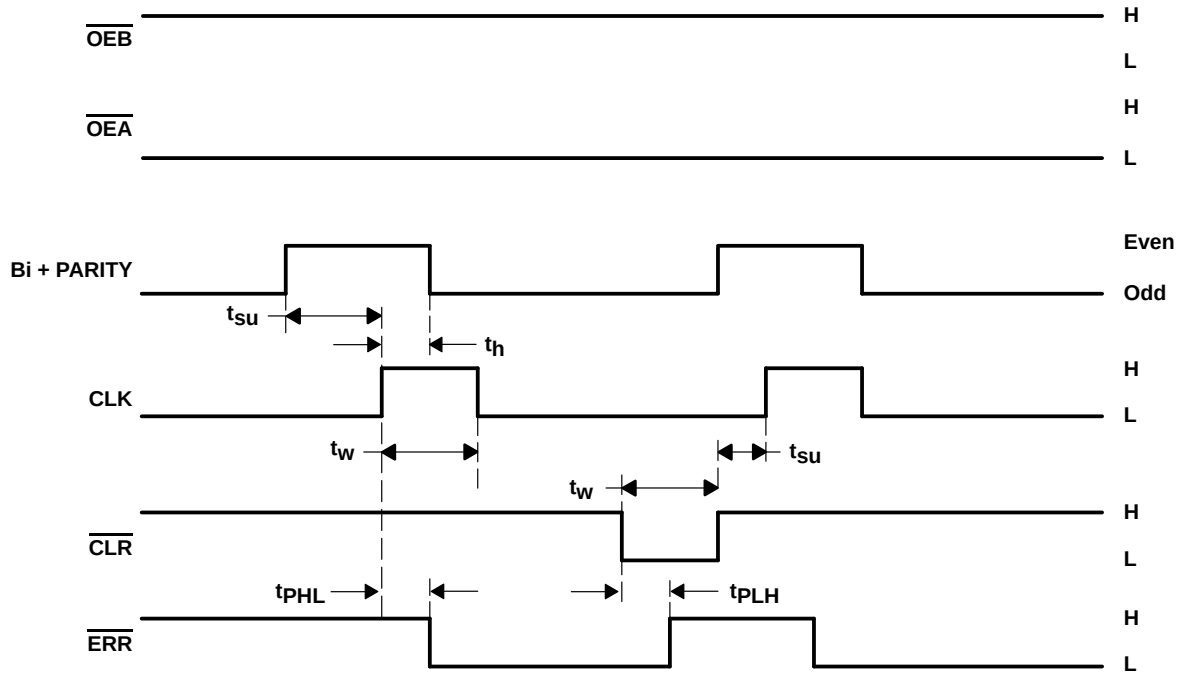
Pin numbers shown are for the DW, JT, and NT packages.

ERROR-FLAG FUNCTION TABLE

INPUTS		INTERNAL TO DEVICE	OUTPUT PRE-STATE	OUTPUT $\overline{ERR}$	FUNCTION
$\overline{CLR}$	CLK	POINT P	$\overline{ERR}_{n-1}$†		
H	↑	H	H	H	Sample
H	↑	X	L	L	
H	↑	L	X	L	
L	X	X	X	H	Clear

† The state of the $\overline{ERR}$ output before any changes at $\overline{CLR}$, CLK, or point P

error-flag waveforms



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V_{CC} . . . . . –0.5 V to 7 V
Input voltage range, V_I (except I/O ports) (see Note 1) . . . . . –0.5 V to 7 V
Voltage range applied to any output in the high state or power-off state, V_O . . . . . –0.5 V to 5.5 V
Current into any output in the low state, I_O: SN54ABT833 . . . . . 96 mA
SN74ABT833 . . . . . 128 mA
Input clamp current, I_{IK} (V_I < 0) . . . . . –18 mA
Output clamp current, I_{OK} (V_O < 0) . . . . . –50 mA
Maximum power dissipation at T_A = 55°C (in still air) (see Note 2): DW package . . . . . 1.7 W
NT package . . . . . 1.3 W
Storage temperature range, T_{stg} . . . . . –65°C to 150°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
2. The maximum package power dissipation is calculated using a junction temperature of 150°C and a board trace length of 750 mils, except for the NT package, which has a trace length of zero. For more information, refer to the *Package Thermal Considerations* application note in the 1994 *ABT Advanced BiCMOS Technology Data Book*, literature number SCBD002B.

recommended operating conditions (see Note 3)

			SN54ABT833		SN74ABT833		UNIT
			MIN	MAX	MIN	MAX	
V_{CC}	Supply voltage		4.5	5.5	4.5	5.5	V
V_{IH}	High-level input voltage		2		2		V
V_{IL}	Low-level input voltage			0.8		0.8	V
V_I	Input voltage		0	V_{CC}	0	V_{CC}	V
V_{OH}	High-level output voltage	$\overline{ERR}$		5.5		5.5	V
I_{OH}	High-level output current	Except $\overline{ERR}$		–24		–32	mA
I_{OL}	Low-level output current			48		64	mA
$\Delta t/\Delta v$	Input transition rise or fall rate	Outputs enabled		5		5	ns/V
T_A	Operating free-air temperature		–55	125	–40	85	°C

NOTE 3: Unused or floating pins (input or I/O) must be held high or low.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS			T_A = 25°C			SN54ABT833		SN74ABT833		UNIT
					MIN	TYP†	MAX	MIN	MAX	MIN	MAX	
V_{IK}		V_{CC} = 4.5 V,	I_I = –18 mA				–1.2		–1.2		–1.2	V
V_{OH}	All outputs except $\overline{ERR}$	V_{CC} = 4.5 V,	I_{OH} = –3 mA		2.5			2.5		2.5		V
		V_{CC} = 5 V,	I_{OH} = –3 mA		3			3		3		
		V_{CC} = 4.5 V	I_{OH} = –24 mA		2			2				
			I_{OH} = –32 mA		2*					2		
V_{OL}		V_{CC} = 4.5 V	I_{OL} = 24 mA				0.55		0.55			V
			I_{OL} = 64 mA				0.55*				0.55	
I_{OH}	$\overline{ERR}$	V_{CC} = 4.5 V,	V_{OH} = 5.5 V				20		20		20	µA
I_I	Control inputs	V_{CC} = 5.5 V,	V_I = V_{CC} or GND				±1		±1		±1	µA
	A or B ports						±100		±100		±100	
I_{IL}	A or B ports	V_{CC} = 0,	V_I = GND				–50		–50		–50	µA
I_{OZH}‡		V_{CC} = 5.5 V,	V_O = 2.7 V				50		50		50	µA
I_{OZL}‡		V_{CC} = 5.5 V,	V_O = 0.5 V				–50		–50		–50	µA
I_{off}		V_{CC} = 0,	V_I or $V_O \le$ 4.5 V				±100				±100	µA
I_{CEX}		V_{CC} = 5.5 V,	V_O = 5.5 V	Outputs high			50		50		50	µA
I_O§		V_{CC} = 5.5 V,	V_O = 2.5 V		–50	–100	–200#	–50	–200#	–50	–200#	mA
I_{CC}		V_{CC} = 5.5 V, I_O = 0, V_I = V_{CC} or GND	A or B ports	Outputs high		1	250		250		250	µA
				Outputs low		24	38#		38#		38#	mA
				Outputs disabled		0.5	250		250		250	µA
ΔI_{CC}¶		V_{CC} = 5.5 V, One input at 3.4 V, Other inputs at V_{CC} or GND	Data inputs	Output enabled			1.5		1.5		1.5	mA
				Outputs disabled			50		50		50	µA
			Control inputs				1.5		1.5		1.5	mA
C_i	Control inputs	V_I = 2.5 V or 0.5 V				4.5						pF
C_{io}	A or B ports	V_O = 2.5 V or 0.5 V				10.5						pF

* On products compliant to MIL-STD-883, Class B, this parameter does not apply.
† All typical values are at V_{CC} = 5 V.
‡ The parameters I_{OZH} and I_{OZL} include the input leakage current.
§ Not more than one output should be tested at a time, and the duration of the test should not exceed one second.
¶ This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND.
# These limits may vary among suppliers.

timing requirements over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 1)

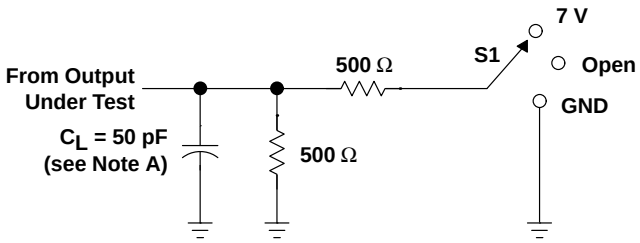
			V_{CC} = 5 V, T_A = 25°C		SN54ABT833		SN74ABT833		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	
t_w	Pulse duration	CLK high or low	3		3		3		ns
		$\overline{CLR}$ low	3		3		3		
t_{su}	Setup time before CLK↑	B or PARITY high	9.8		9.8		9.8		ns
		B or PARITY low	8.1		8.1		8.1		
		$\overline{CLR}$	2		2		2		
t_h	Hold time after CLK↑	B or PARITY	0		0		0		ns

switching characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V_{CC} = 5 V, T_A = 25°C			SN54ABT833		SN74ABT833		UNIT
			MIN	TYP†	MAX	MIN	MAX	MIN	MAX	
t_{PLH}	A or B	B or A	1.2	2.8	4.8	1.2	5.4	1.2	5.3	ns
t_{PHL}			1	3	4.8‡	1	5.4	1	5.3‡	
t_{PLH}	A	PARITY	2.1	5.5	9.5	2.1	11.3	2.1	11.2	ns
t_{PHL}			2.5	5.3	9.7	2.5	11.1	2.5	11	
t_{PZH}	$\overline{OE}$	PARITY	2.6	6.2	8.5	2.6	10.6	2.6	10.5	ns
t_{PZL}			2.6‡	5.8	8.6	2.6‡	10.1	2.6‡	10	
t_{PLH}	$\overline{CLR}$	$\overline{ERR}$	1	3.2	4.8‡	1	5.3	1	5.2	ns
t_{PHL}	CLK		1.2‡	2.8	5.7	1.2‡	6.3	1.2‡	6.2	
t_{PZH}	$\overline{OE}$	A, B or PARITY	1	3.7	5.8‡	1	6.6	1	6.5‡	ns
t_{PZL}			1.3‡	3.8	5.8	1.3‡	6.6	1.3‡	6.5‡	
t_{PHZ}	$\overline{OE}$	A, B or PARITY	1.9‡	4.4	7.3	1.9‡	8	1.9‡	7.9	ns
t_{PLZ}			2.2‡	4.4	7.7	2.2‡	8.2	2.2‡	8.1	

† All typical values are at V_{CC} = 5 V.
‡ These limits may vary among suppliers.

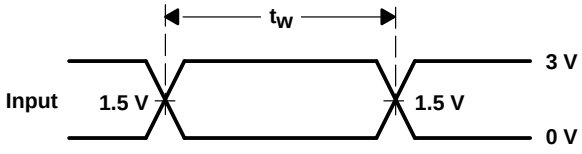
PARAMETER MEASUREMENT INFORMATION



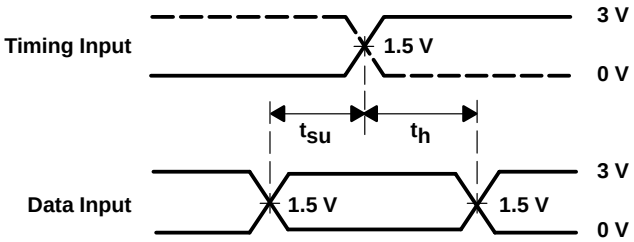
TEST	S1
t_{PLH}/t_{PHL}	Open
t_{PLZ}/t_{PZL}	7 V
t_{PHZ}/t_{PZH}	Open

$\overline{ERR}$	S1
t_{PHL}	7 V
t_{PLH}	7 V

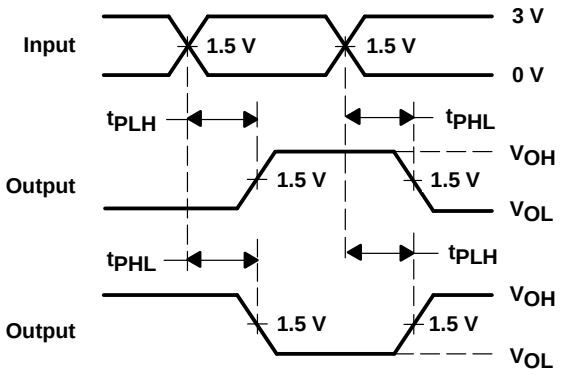
LOAD CIRCUIT FOR OUTPUTS



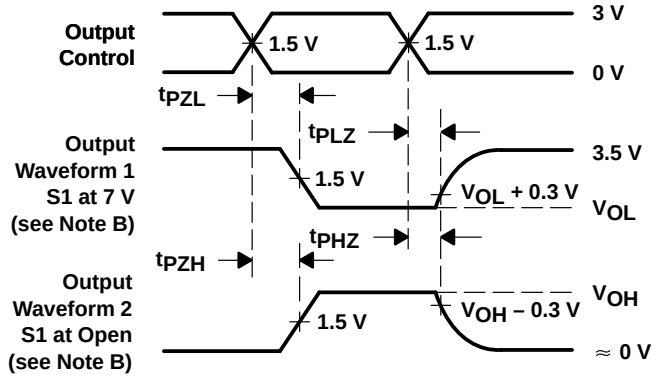
VOLTAGE WAVEFORMS
PULSE DURATION



VOLTAGE WAVEFORMS
SETUP AND HOLD TIMES



VOLTAGE WAVEFORMS
PROPAGATION DELAY TIMES
INVERTING AND NONINVERTING OUTPUTS



VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES
LOW- AND HIGH-LEVEL ENABLING

NOTES: A. C_L includes probe and jig capacitance.
B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z_O = 50 Ω, t_r ≤ 2.5 ns, t_f ≤ 2.5 ns.
D. The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

PRODUCT PREVIEW

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